

Agent's Docket No. 12591-US

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	)	
Siegfried JANZ et al	)	
Serial No: <b>20/</b> 054,911	) Art Unit: <b>2874</b>	
Filed: 25-January-2002	) ) Examiner:	

For: METHOD FOR POLARIZATION BIREFRINGENCE COMPENSATION IN A WAVEGUIDE DEMULTIPLEXER USING A COMPENSATOR WITH A HIGH REFRACTIVE INDEX CAPPING LAYER

April 5, 2002

Commissioner of Patent and Trademarks

Washington, D.C. 20231

#### TRANSMITTAL LETTER

Sir:

Please find enclosed for filing:

- Response to Notice of Omitted Items dated February 11, 2002
- Marked up Version to Show Changes Made

Respectfully submitted,

George M. MacGregor Registration No. 37,547

Agent of Record

**MARKS & CLERK** P. O. Box 957, Station B, Ottawa, Ontario Canada K1P 5S7 (613) 236-9561



Agent's Docket No. 12591-US

# IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of	)	
Siegfried JANZ et al	)	
Serial No: <b>09/054,911</b>	) Art Unit: 2874	
Filed: 25-January-2002	) Examiner:	

For: METHOD FOR POLARIZATION BIREFRINGENCE COMPENSATION IN A WAVEGUIDE DEMULTIPLEXER USING A COMPENSATOR WITH A HIGH REFRACTIVE INDEX CAPPING LAYER

April 5, 2002

Commissioner of Patent and Trademarks

Washington, D.C. 20231

## RESPONSE TO NOTICE OF OMITTED ITEM(S) DATED FEBRUARY 11, 2002

Sir:

In response to the Notice of Omitted Items dated February 11, 2002, applicants respectfully request that the application be amended as follows by way of Preliminary Amendment:

### In the Specification:

Please cancel the paragraph on page 5, at line 14 and 15.

Please replace the paragraph on page 11, beginning at line 9 with the following rewritten paragraph:

-- In a further embodiment, a lower refractive index overlying layer of  $SiO_2$  ( $N \cong 1.46$ ) is deposited on top of the silicon nitride layer 15 ( $N \cong 1.9$ ). The strength of the compensator is adjusted by varying the thickness of this overlying  $SiO_2$  layer. The change in  $\Delta\lambda$  with oxide thickness is now approximately three times smaller than for an identical change in the thickness of the nitride layer 15. --